

IGBT MODULE (S series) 600V / 75A / PIM



■ Features

- Low $V_{CE(sat)}$
- Compact package
- P.C. board mount
- Converter diode bridge, Dynamic brake circuit

■ Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply

■ Maximum ratings and characteristics

● Absolute maximum ratings ($T_c=25^\circ\text{C}$ unless without specified)

Item	Symbol	Condition	Rating	Unit
Inverter	Collector-Emitter voltage	V_{CES}	600	V
	Gate-Emitter voltage	V_{GES}	± 20	V
	Collector current	I_C Continuous	75	A
		I_{CP} 1ms	150	A
		$-I_C$	75	A
	Collector power dissipation	P_C 1 device	300	W
Brake	Collector-Emitter voltage	V_{CES}	600	V
	Gate-Emitter voltage	V_{GES}	± 20	V
	Collector current	I_C Continuous	50	A
		I_{CP} 1ms	100	A
	Collector power dissipation	P_C 1 device	200	W
Converter	Repetitive peak reverse voltage	V_{RRM}	600	V
	Repetitive peak reverse voltage	V_{RRM}	800	V
	Average output current	I_O 50Hz/60Hz sine wave	75	A
	Surge current (Non-Repetitive)	I_{FSM} $T_j=150^\circ\text{C}$, 10ms	525	A
	I^2t (Non-Repetitive)	I^2t half sine wave	1378	A^2s
	Operating junction temperature	T_j	+150	$^\circ\text{C}$
	Storage temperature	T_{stg}	-40 to +125	$^\circ\text{C}$
	Isolation between terminal and copper base *2	V_{iso} AC : 1 minute	AC 2500	V
	voltage between thermistor and others *3		AC 2500	V
	Mounting screw torque		3.5 *1	N·m

*1 Recommendable value : 2.5 to 3.5 N·m (M5)

*2 All terminals should be connected together when isolation test will be done.

*3 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

● Electrical characteristics (T_j=25°C unless otherwise specified)

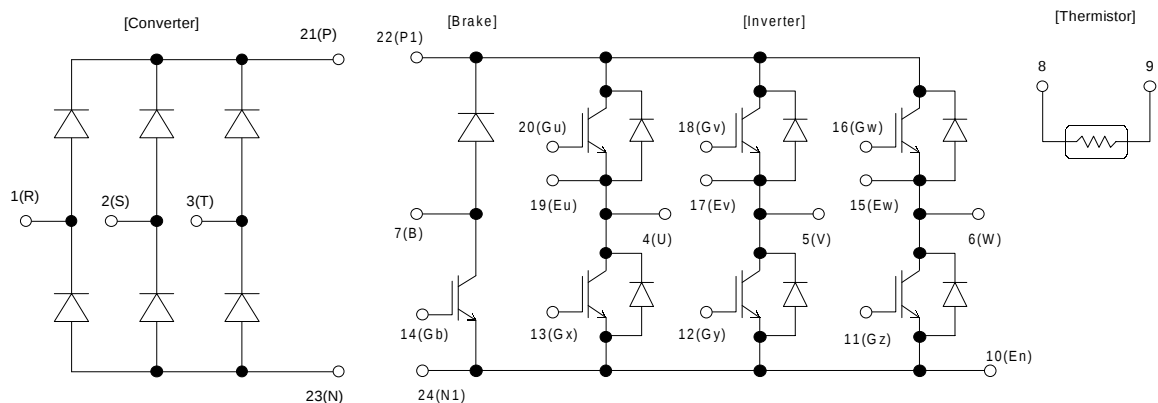
Item		Symbol	Condition	Characteristics			Unit
				Min.	Typ.	Max.	
Inverter	Zero gate voltage collector current	I _{CES}	V _{CE} =600V, V _{GE} =0V			1.0	mA
	Gate-Emitter leakage current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			0.2	μA
	Gate-Emitter threshold voltage	V _{GE(th)}	V _{CE} =20V, I _C =75mA	5.5	7.8	8.5	V
	Collector-Emitter saturation voltage	V _{CE(sat)}	V _{GE} =15V, I _C =75A	chip	1.8		V
			terminal		2.1	2.55	
	Input capacitance	C _{ies}	V _{GE} =0V, V _{CE} =10V, f=1MHz		7500		pF
	Turn-on time	t _{on}	V _{CC} =300V		0.45	1.2	μs
		t _r	I _C =75A		0.25	0.6	
		t _{r(i)}	V _{GE} =±15V		0.08		
	Turn-off	t _{off}	R _G =33Ω		0.40	1.0	
		t _f			0.05	0.35	
Brake	Forward on voltage	V _F	I _F =75A	chip	1.7		V
			terminal		2.0	2.7	
	Reverse recovery time of FRD	t _{rr}	I _F =75A			0.3	μs
	Zero gate voltage collector current	I _{CES}	V _{CE} =600V, V _{GE} =0V			1.0	mA
	Gate-Emitter leakage current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			0.2	μA
	Collector-Emitter saturation voltage	V _{CE(sat)}	I _C =50A, V _{GE} =15V	chip	1.8		V
			terminal		2.05	2.5	
	Turn-on time	t _{on}	V _{CC} =300V		0.45	1.2	μs
		t _r	I _C =50A		0.25	0.6	
	Turn-off time	t _{off}	V _{GE} =±15V		0.40	1.0	
		t _f	R _G =51Ω		0.05	0.35	
Converter	Reverse current	I _{RRM}	V _R =600V			1.0	mA
	Forward on voltage	V _{FM}	I _F =75A	chip	1.1		V
			terminal		1.2	1.5	
Thermistor	Reverse current	I _{RRM}	V _R =800V			1.0	mA
	Resistance	R	T=25°C		5000		Ω
			T=100°C	465	495	520	
	B value	B	T=25/50°C	3305	3375	3450	K

● Thermal resistance Characteristics

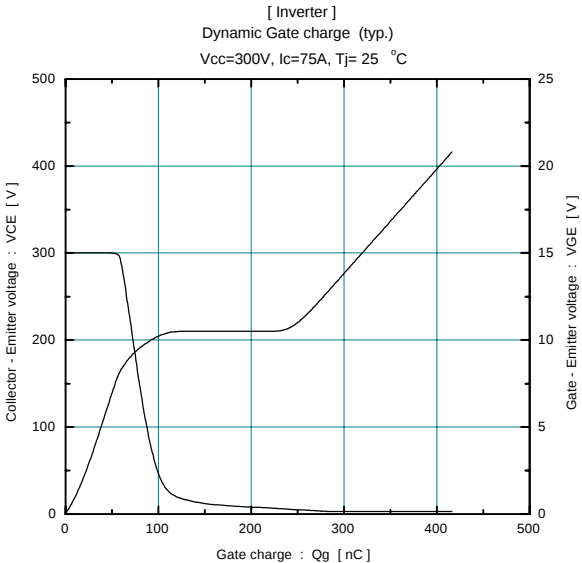
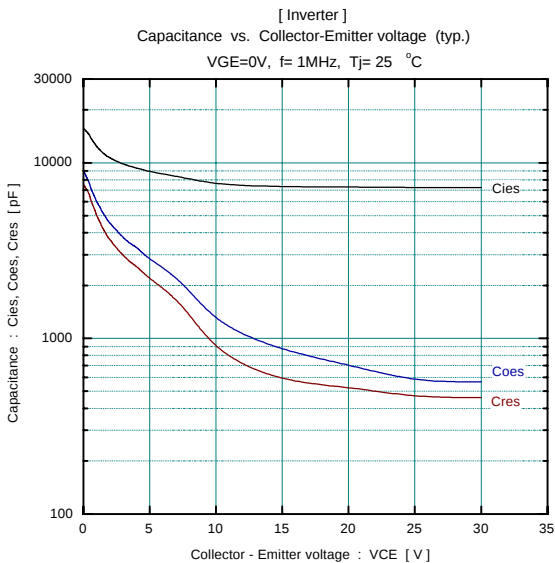
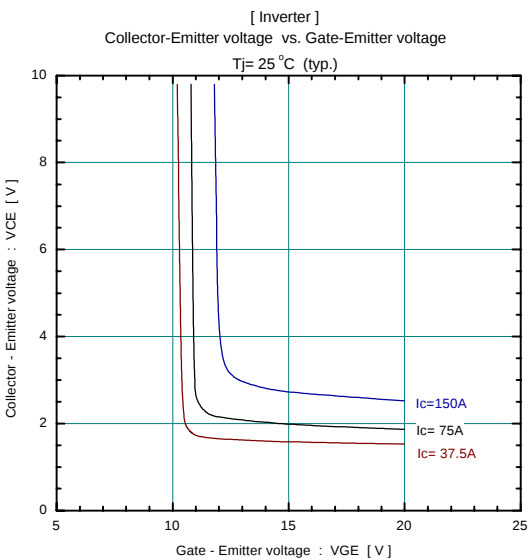
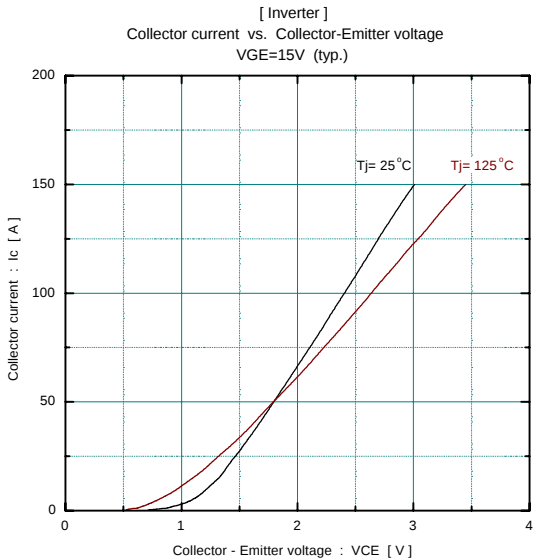
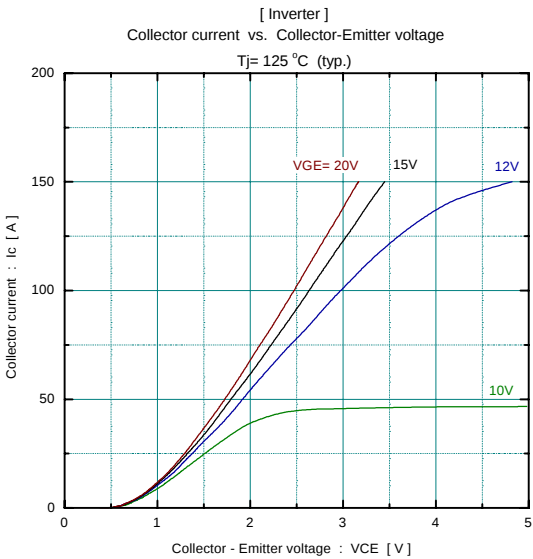
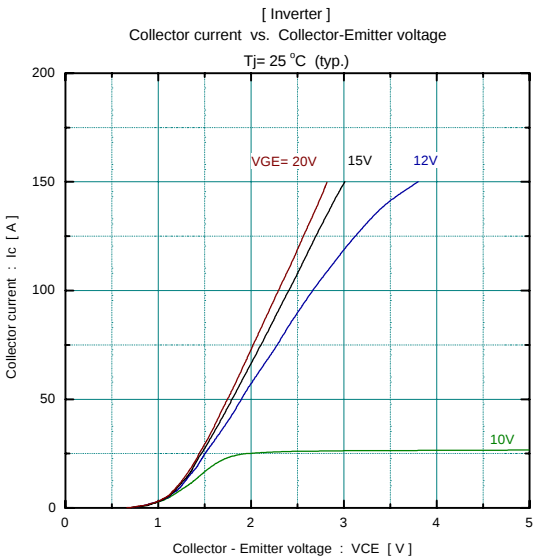
Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance (1 device)	R _{th(j-c)}	Inverter IGBT			0.42	°C/W
		Inverter FWD			0.90	
		Brake IGBT			0.63	
		Converter Diode			0.70	
Contact thermal resistance *	R _{th(c-f)}	With thermal compound		0.05		

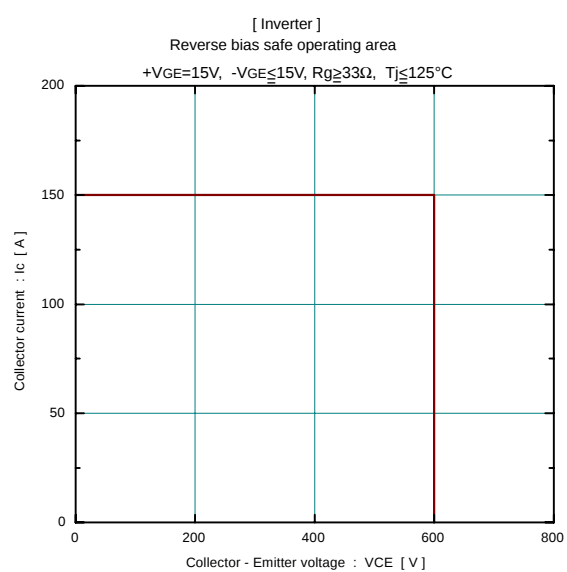
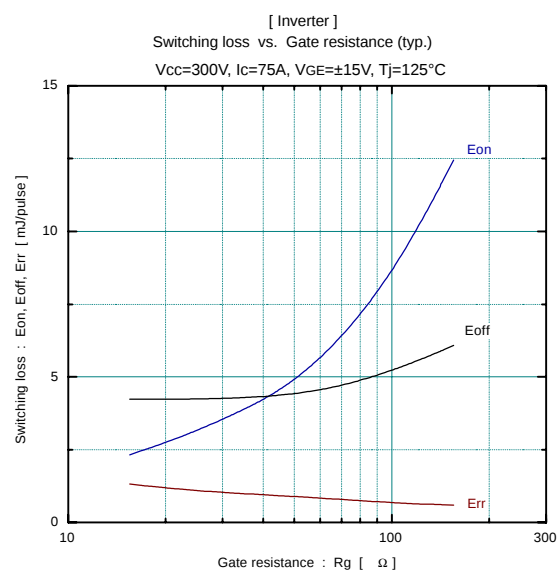
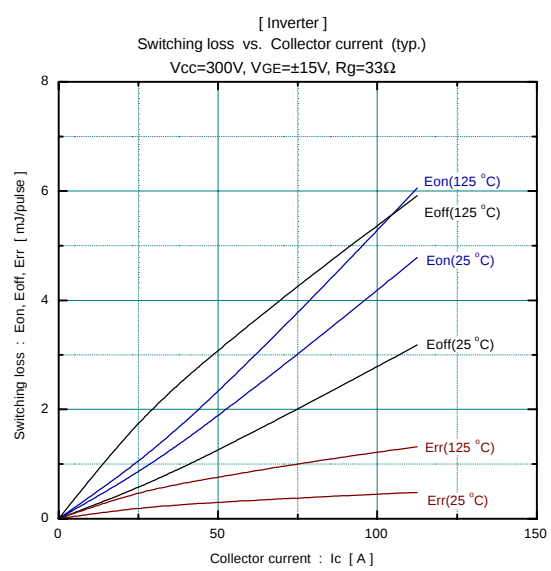
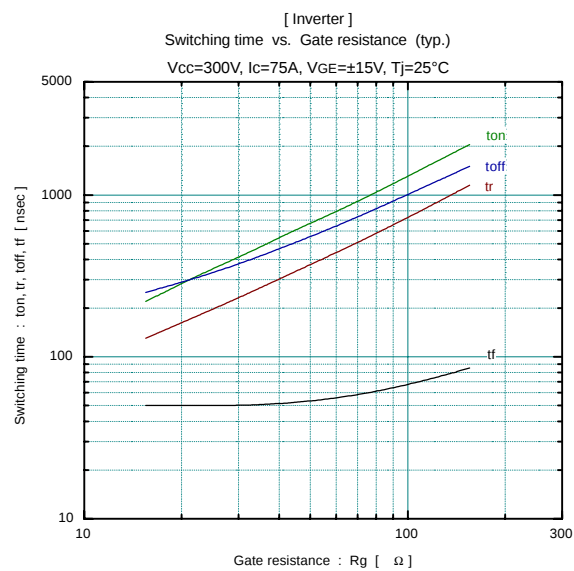
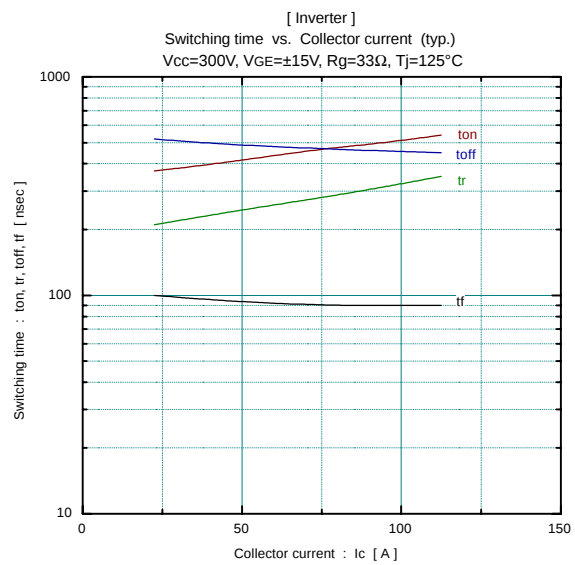
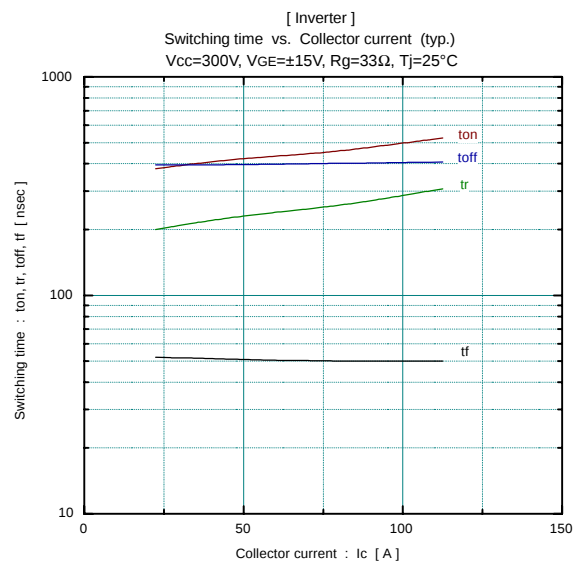
* This is the value which is defined mounting on the additional cooling fin with thermal compound

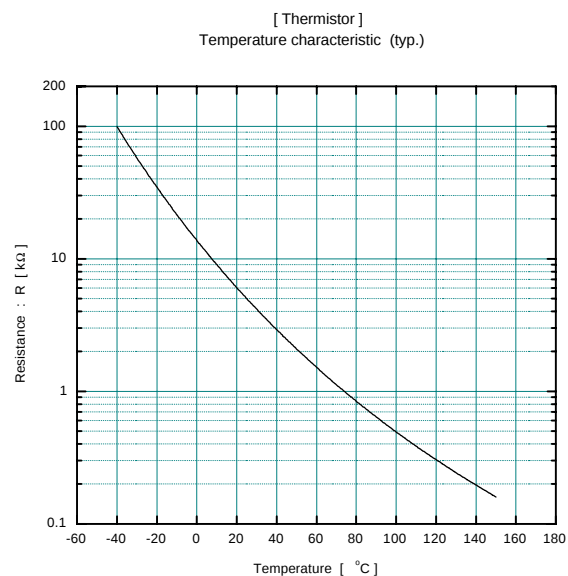
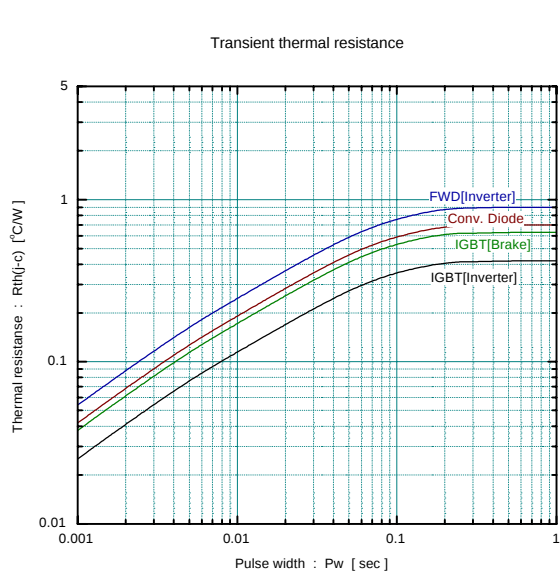
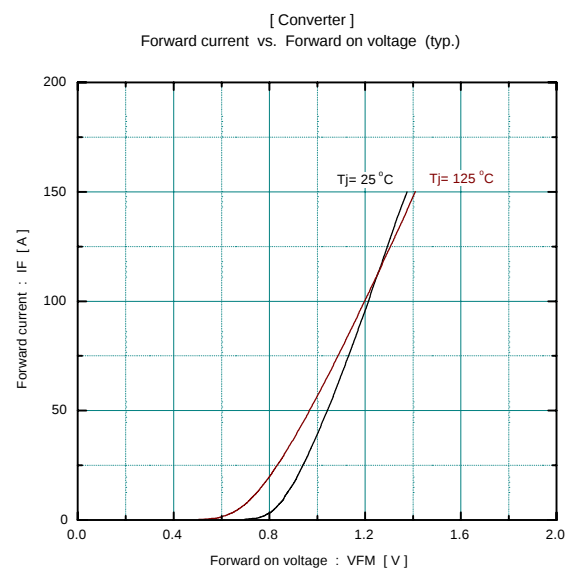
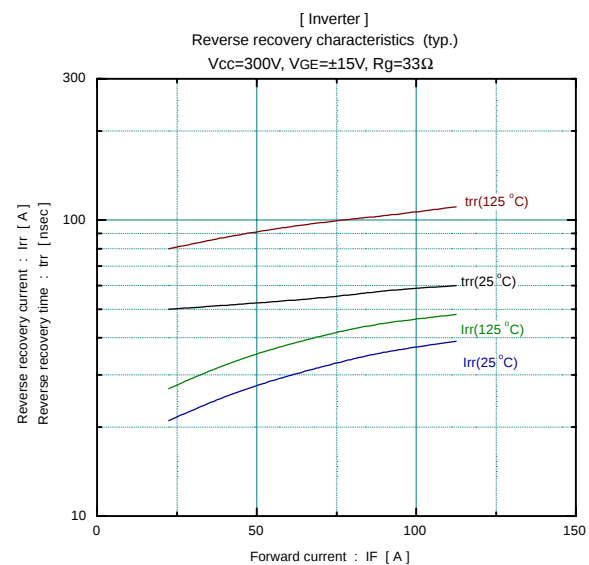
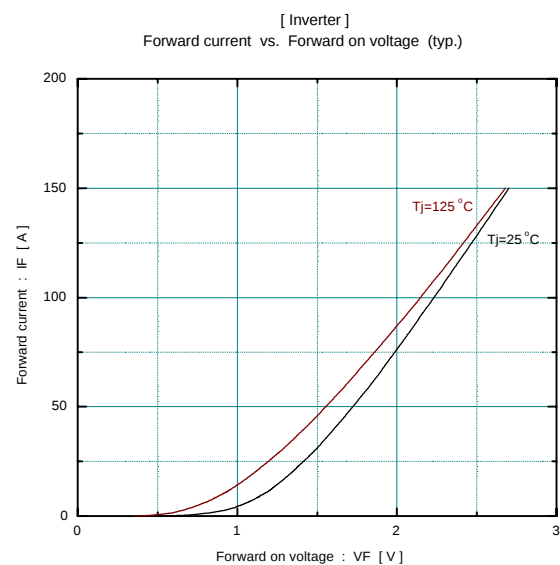
■ Equivalent Circuit Schematic

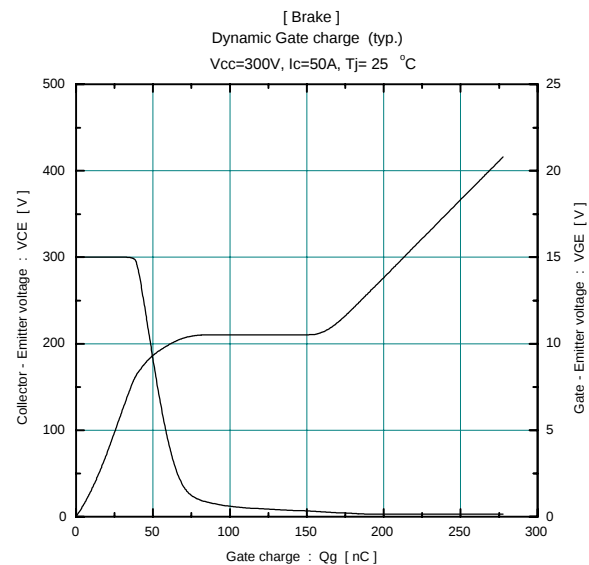
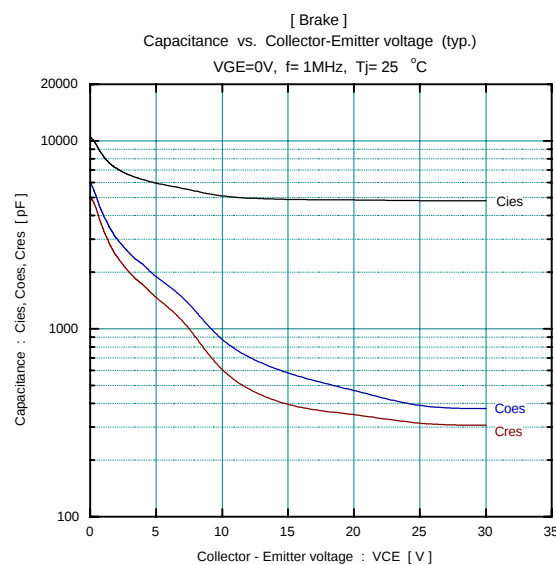
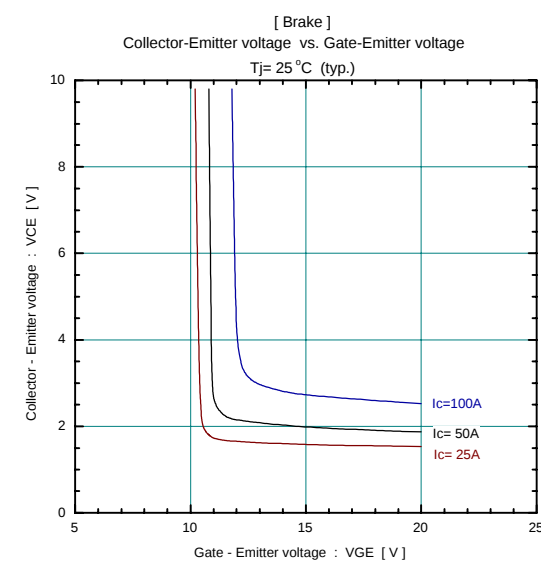
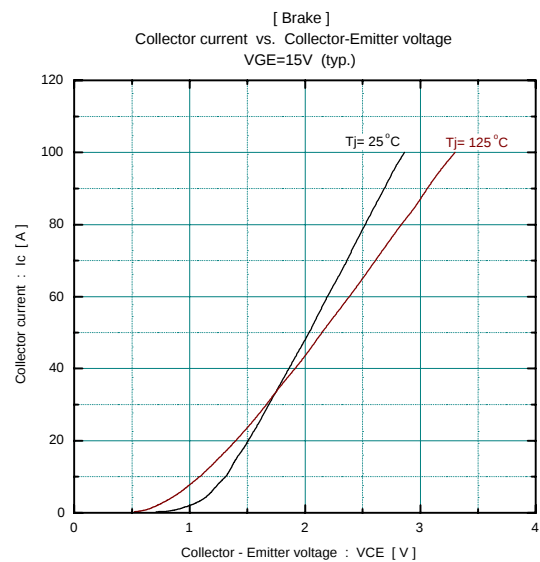
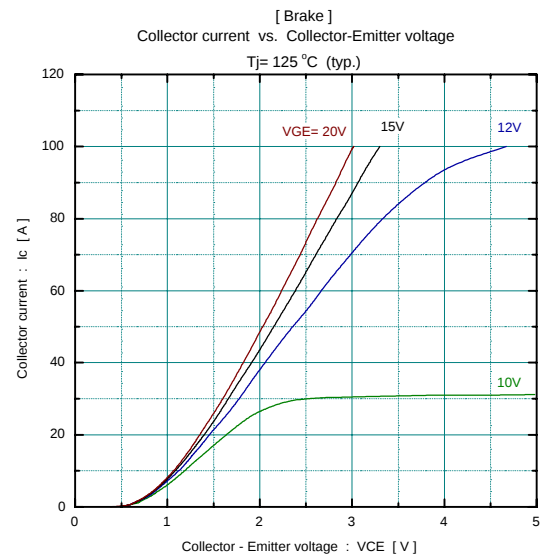
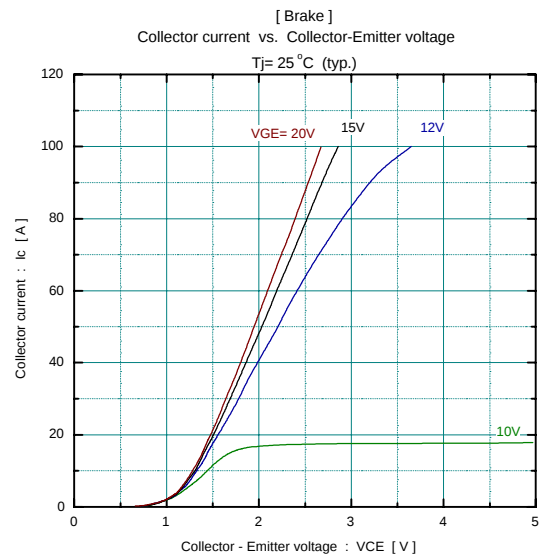


■ Characteristics (Representative)

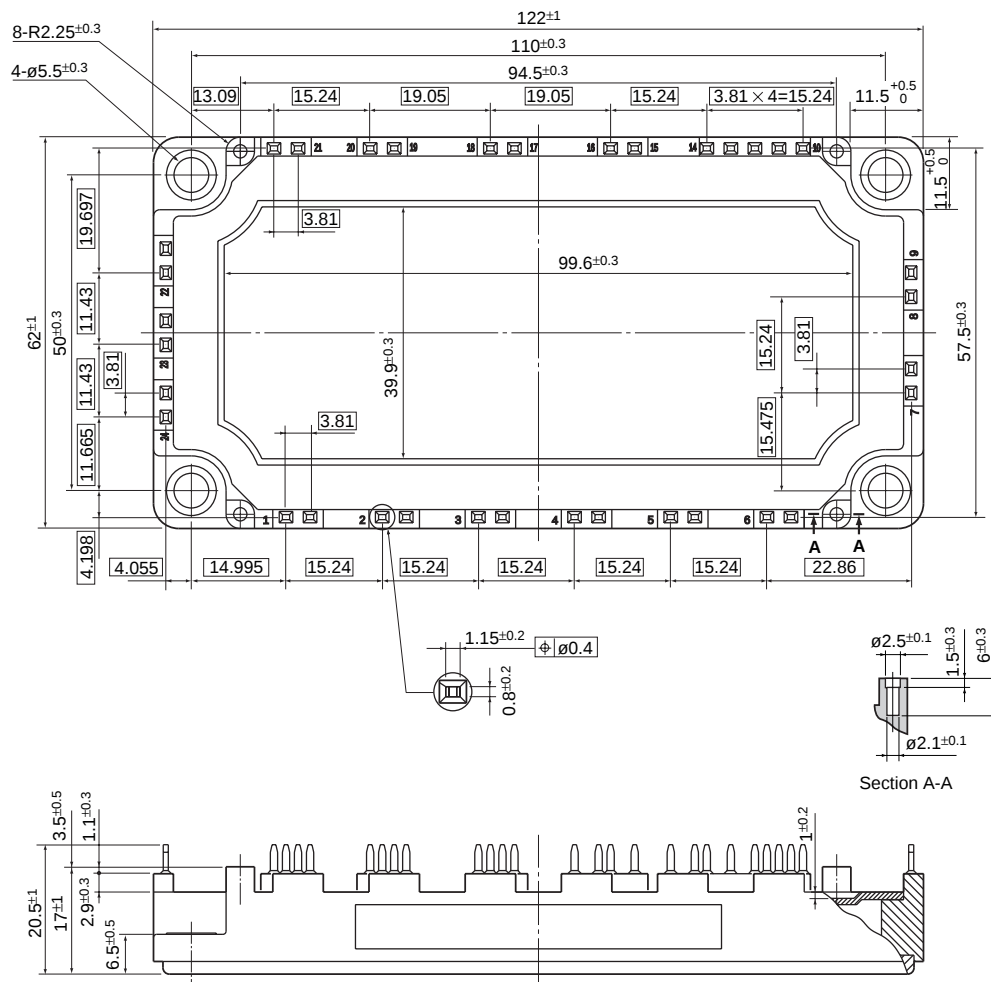








■ Outline Drawings, mm



☐ Shows theory dimensions